



DMTH4002SCTBQ

40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET TO263AB

Product Summary

BV _{DSS}	Rds(on) Max	I _D Tc = +25°С
40V	$3m\Omega @ V_{GS} = 10V$	192A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

Features

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low R_{DS(ON)}—Minimizes Power Losses
- Low Q_g—Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4002SCTBQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

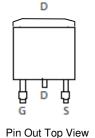
https://www.diodes.com/guality/product-definitions/

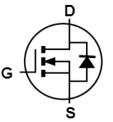
Mechanical Data

- Case: TO263AB
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 1.7 grams (Approximate)



Top View





Internal Schematic

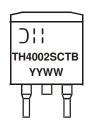
Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH4002SCTBQ-13	TO263AB (D2PAK)	800/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2), & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



TH4002SCTB = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 20 = 2020) WW = Week (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	40	V
Gate-Source Voltage		VGSS	±20	V
Continuous Drain Current (Note 6)	$T_{\rm C} = +25^{\circ}{\rm C}$	l-	192	٨
Continuous Drain Current (Note 6)	Tc = +100°C	ID	136	А
Maximum Continuous Body Diode Forward Current (Note 6)	$T_{\rm C} = +25^{\circ}{\rm C}$	ls	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		ldм	760	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	760	А
Avalanche Current, L = 3mH		I _{AS}	19.2	А
Avalanche Energy, L = 3mH		Eas	551.8	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	6	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	25	°C/W
Total Power Dissipation (Note 6)	$T_{\rm C} = +25^{\circ}{\rm C}$	PD	166.7	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +175	°C

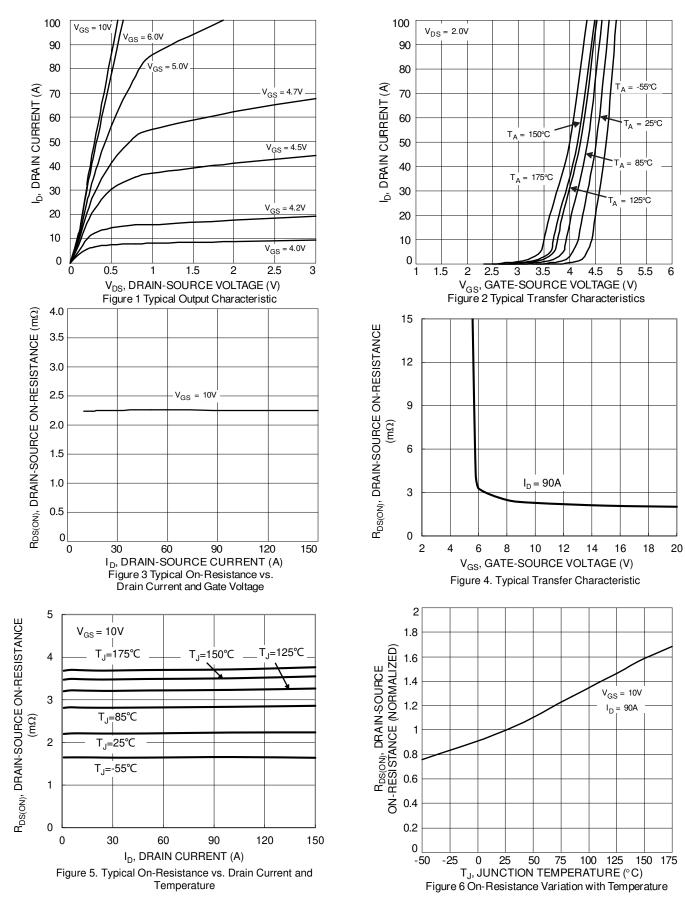
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						÷	
Drain-Source Breakdown Voltage	BV _{DSS}	40	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μΑ	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2	-	4	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	2.22	3	mΩ	$V_{GS} = 10V, I_{D} = 90A$	
Diode Forward Voltage	Vsd	—	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	7180	—		$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	—	1698	—	pF		
Reverse Transfer Capacitance	Crss	_	17	_			
Gate Resistance	Rg	_	1.04	—	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	77.5	_		$\label{eq:VDD} \begin{array}{l} V_{DD} = 20V, \ I_D = 90A, \\ V_{GS} = 10V \end{array}$	
Gate-Source Charge	Qgs	_	23.6	_	nC		
Gate-Drain Charge	Q _{gd}	_	13.6	_			
Turn-On Delay Time	t _{D(ON)}		16.8	_		$\label{eq:VDD} \begin{split} V_{DD} &= 20V, V_{GS} = 10V, \\ I_D &= 90A, R_G = 3.5\Omega \end{split}$	
Turn-On Rise Time	tR		8.0	_			
Turn-Off Delay Time	tD(OFF)	_	35.8	_	ns		
Turn-Off Fall Time	tF		11.6	_			
Reverse Recovery Time	t _{RR}	_	46.36	_	ns	L 154 di/dt 1004/up	
Reverse Recovery Charge	Q _{RR}	_	56.11	—	nC	- I _F = 15A, di/dt = 100A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

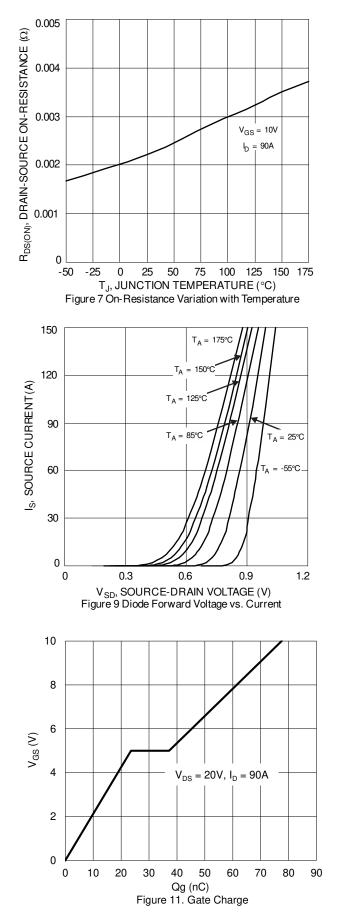


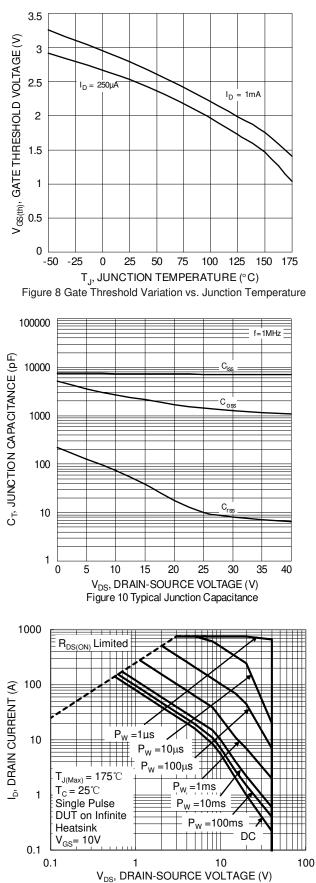
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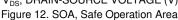




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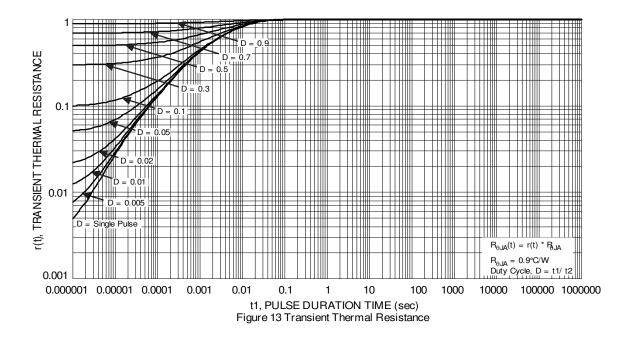






DMTH4002SCTBQ Document number: DS40950 Rev. 3 - 2

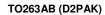


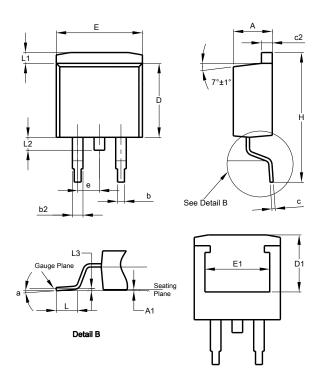




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



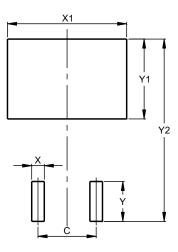


TO263AB (D2PAK)					
Dim	Min	Max	Тур		
Α	4.07	4.82	_		
A1	0.00	0.25	—		
b	0.51	0.99	—		
b2	1.15	1.77	_		
С	0.356	0.73	_		
c2	1.143	1.65	_		
D	8.39	9.65	—		
D1	6.55	6.95			
е		2.54 TYP			
E	9.66	10.66	_		
E1	6.23	8.23	_		
Н	14.61	15.87	_		
L	1.78	2.79	_		
L1	_	1.67	_		
L2	_	1.77	_		
L3	—	_	0.254		
а	0°	8°	_		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO263AB (D2PAK)



Dimensions	Value (in mm)
С	5.08
Х	1.10
X1	10.41
Y	3.50
Y1	7.01
Y2	15.99



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